TOSHIBA Photocoupler Photorelay

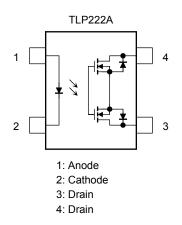
TLP222A, TLP222A-2

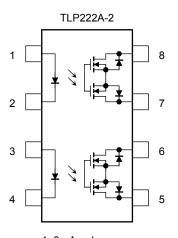
Telecommunications
Measurement and Control Equipment
Data Acquisition System
Measurement Equipment

The Toshiba TLP222A and TLP222A-2 consist of a gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a DIP package whose withstanding voltage is 60 V. These photorelays have higher output current rating than phototransistor-type photocoupler; hence, they are suitable for use as On/Off control for high current.

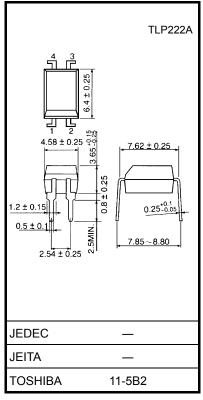
- Normally open (1-form-A and 2-form-A) devices
- Peak off-state voltage: 60 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 500 mA (max)
- On-state resistance: 2Ω (max)
- Isolation voltage: 2500 Vrms (min)
- UL recognized: UL1557, File No.E67349

Pin Configuration (top view)

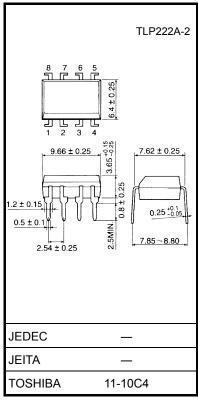




1, 3 : Anode 2, 4 : Cathode 5 : Drain D1 6 : Drain D2 7 : Drain D3 8 : Drain D4 Unit: mm



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)



Absolute Maximum Rating (Ta = 25°C)

Characteristics				Symbol	Rating	Unit	
	Forward current			lF	50	mA	
	Forward curr	ent derating (Ta ≧ 25°C)	ΔI _F /°C	-0.5	mA/°C	
LED	Peak forward	d current		I _{FP}	1	Α	
	Reverse volt	age		V _R	5	V	
	Junction tem	perature		Тj	125	°C	
	Off-state output terminal voltage			V _{OFF}	60	V	
		TLP222A					
	On-state current	TLP222A-2	One channel operation	I _{ON}	500	mA	
Detector		TLI ZZZA-Z	Two channel operations				
Detector	Forward current derating	TLP222A		ΔΙ _{ΟΝ} /°C			
		TLP222A-2	One channel operation		-5.0	mA/°C	
	(Ta ≧ 25°C)	TLF222A-2	Two channel operations				
	Junction tem	perature		Тj	125	°C	
Storage temperature			T _{stg}	-55 to 125	°C		
Operating temperature			T _{opr}	-40 to 85	°C		
Lead soldering temperature (10 s)			T _{sol}	260	°C		
Isolation voltage (AC, 1 min, R.H. ≦ 60%) (Note 1)				BVS	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: LED pins are shorted together. Detector pins are also shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V_{DD}	_	_	48	V
Forward current	lF	5	7.5	25	mA
On-state current	I _{ON}	_	_	500	mA
Operating temperature	T _{opr}	-20		65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V	_	_	10	μА
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	_	pF
Detector	Off-state current	l _{OFF}	V _{OFF} = 60 V	_	_	1	μА
	Capacitance	C _{OFF}	V = 0, f = 1 MHz	_	130	_	pF

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Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}	I _{ON} = 500 mA	_	1.6	3	mA
Return LED current	I _{FC}	I _{OFF} = 100 μA	0.1	_	_	mA
On-state resistance	R _{ON}	$I_{ON} = 500 \text{ mA}, I_{F} = 5 \text{ mA}$	_	1	2	Ω

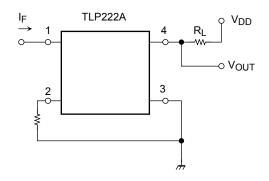
Isolation Characteristics (Ta = 25°C)

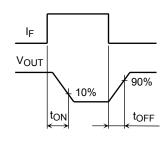
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≦ 60%	5×10^{10}	10 ¹⁴	_	Ω
	BVS	AC, 1 min	2500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	_	5000	_	VIIIIS
		DC, 1 min, in oil	_	5000	_	Vdc

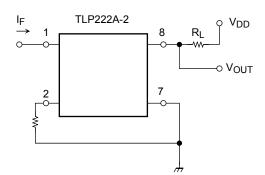
Switching Characteristics (Ta = 25°C)

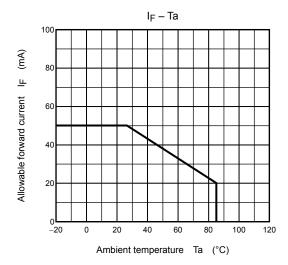
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t _{ON}	$R_L = 200 \Omega$	_	0.8	2	ms
Turn-off time	toff	$V_{DD} = 20 \text{ V, I}_{F} = 5 \text{ mA}$ (Note 2)	_	0.1	0.5	1113

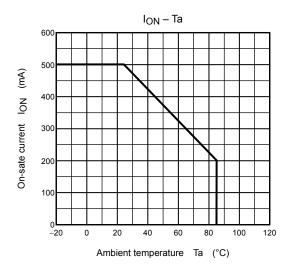
Note 2: Switching time test circuit

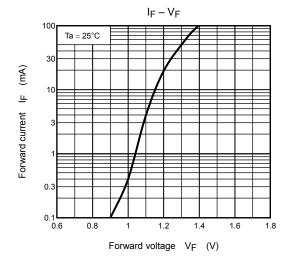


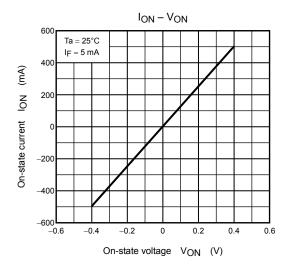


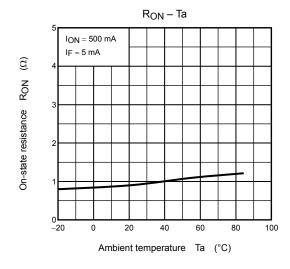


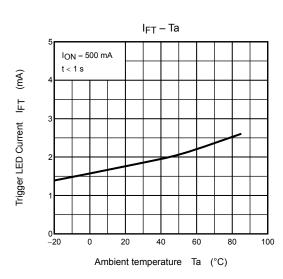


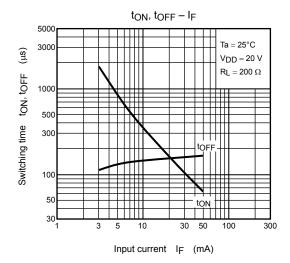


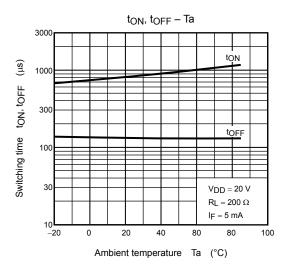


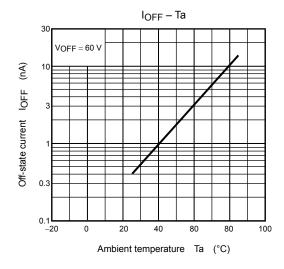












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